

IGBT Discrete

$\mathbf{V}_{\mathbf{CE}}$	600	V
$\mathbf{I}_{\mathbf{C}}$	40	A
V _{CE(SAT)} I _C =40A	1.9	V

Applications

- · Inverter for motor drive
- · AC and DC servo drive amplifier
- Uninterruptible power supply

Features

- High breakdown voltage to 600V for improved reliability
- Maximum junction temperature 175℃
- · Positive temperature coefficient
- . Including fast & soft recovery anti-parallel FWD
- High short circuit capability(10us)

Maximum Ratings ($T_j = 25$ °C unless otherwise specified):

Parameter	Symbol	Value	Unit
Collector-Emitter Breakdown Voltage	$ m V_{CE}$	600	V
DC Collector Current, limited by T_{jmax} $T_C = 25^{\circ}C$ $T_C = 100^{\circ}C$	I_{C}	80 40	A
Diode Forward Current, limited by T_{jmax} T_{C} = 25°C T_{C} = 100°C	\mathbf{I}_{F}	80 40	A
Continuous Gate-Emitter Voltage	V_{GE}	±20	V
Transient Gate-Emitter Voltage (tp≤10μs,D<0.010)	V _{GE}	±30	V
Pulsed Collector Current, V_{GE} =15V, tp limited by T_{jmax}	I _{CM}	200	A
Diode Pulsed Current, tp limited by T _{jmax}	I_{Fpuls}	120	A
Power Dissipation ,Tc=25°C	P _{tot}	310	W
Power Dissipation, Tc=100°C	P _{tot}	145	W

Rev.1.0



Operating Junction Temperature	$T_{\rm j}$	-40+175	°C
Storage Temperature	T_{s}	-55+150	°C
Soldering Temperature, wave soldering 1.6mm (0.063in.) from case for 10s		260	°C

Electrical Characteristics of the IGBT $(T_j=25^{\circ}Cunless otherwise specified)$:

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Static						
Collector-Emitter Breakdown Voltage	BV _{CES}	V _{GE} =0V, I _C =250μA	600		-	V
Gate Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_{C}=1 \text{mA}$	4	5.8	7.5	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V, I _C =40A T _j =25°C, T _j =125°C T _i =150°C		1.98 3.20 3.60	3.30	V
Zero Gate Voltage Collector Current	I_{CES}	V _{CE} =600V, V _{GE} =0V T _j = 25°C, T _j =150°C			0.25 4.00	mA
Gate-Emitter Leakage Current	I _{GES}	V_{CE} = 0V, V_{GE} = ± 20V			±200	nA

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Dynamic						
Input Capacitance	Cies		1	1950	-	
Onput Capacitance	Coes	V_{CE} = 30V, V_{GE} = 0V, f = 1MHz	1	133	-	pF
Reverse Transfer Capacitance	C _{res}		-	16	-	
Gate Charge	Qg		-	234	-	
Gate-Emitter Charge	Q_{ge}	V _{CC} =300V,I _C =40A, V _{GE} =15V	-	41	-	nC
Gate-Collector Charge	Q_{gc}		-	139	-	



Switching Characteristic, Inductive Load (T_j= 25 °C unless otherwise specified):

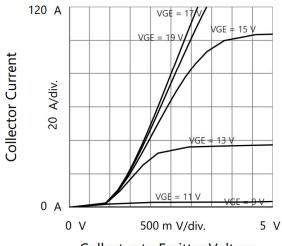
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Turn-on Delay Time	t _{d(on)}		-	32	-	ns
Rise Time	$t_{\rm r}$		-	61	-	ns
Turn-on Energy	Eon	V_{CC} = 300V, I_{C} =20A, V_{GE} = -15V \sim 15V,	-	1.5	-	mJ
Turn-off Delay Time	$t_{d(off)}$	$R_g=12\Omega$	-	127	-	ns
Fall Time	t_{f}		-	50	-	ns
Turn-off Energy	E _{off}		-	0.7	-	mJ

Electrical Characteristics of the DIODE $(T_j=25\,^{\circ}\text{Cunless otherwise specified})$:

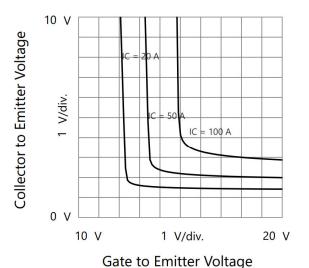
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Diode Forward Voltage	V_{F}	I _F = 20A	-	1.2	2.1	V
Reverse Recovery Current	I_{rr}		-	6	-	A
Reverse Recovery Charge	Q_{rr}	I_F =20A, V_R =300V, di/dt= -200A/ μ s,	-	250	-	nC
Reverse Recovery Energy	Erec		-	0.15		mJ

Thermal Resistance

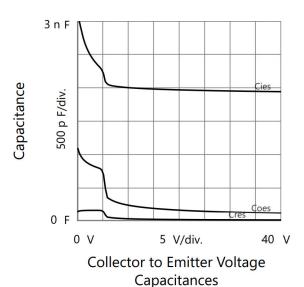
Parameter	Symbol	Max. Value	Unit
IGBT Thermal Resistance, Junction - Case	R _{th} (j-c)	0.45	K/W
Diode Thermal Resistance, Junction - Case	R _{th} (j-c)	1.09	K/W
Thermal Resistance, Junction - Ambient	R _{th} (j-a)	40	K/W

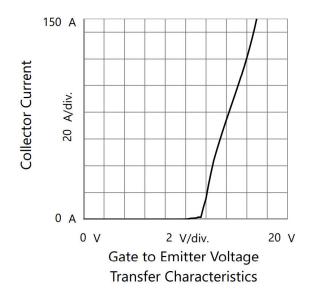


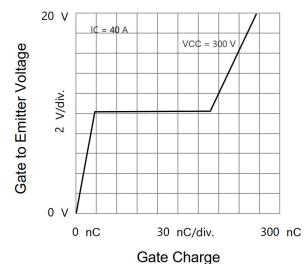
Collector to Emitter Voltage Output Characteristics



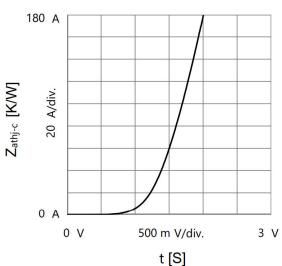
Collector to Emitter Voltage vs. Gate to Emitter Voltage





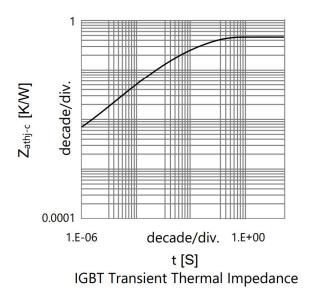


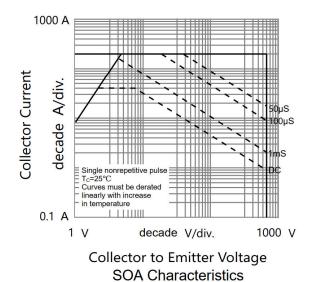
Gate to Emitter Voltage vs. Gate Charge



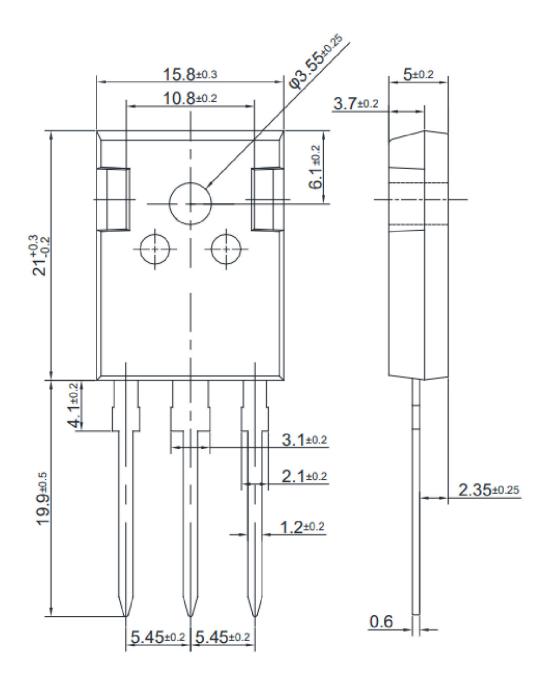
IGBT Transient Thermal Impedance







TO-247 Package Outline Information



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